



**PRODUCT/PROCESS
CHANGE NOTIFICATION
PCN13956– Additional information**

**ST MUAR (Malaysia) capacity increase for LQFP 48 7x7 package
on listed products (Addendum to PCN9484)**

MDG – General Purpose Microcontrollers (GPM) sub-group

What is the change?

	Existing back-end site	Added back-end site
Assembly site	Stats ChipPAC JSCC Jiangyin (China)	ST Muar (Malaysia)
Wire	Gold 0.8mil	Silver 96.5% 0.8mil
Leadframe	Copper Frame Spot Ag	Pre Plated Frame
Leadfinishing (1)	Pure Tin (e3)	Rough Ni Pd AgAu (e4)
Resin (2)	Sumitomo G631SHQ	Sumitomo G700LS
Glue	Ablestik 3230	Hitachi EN4900
Marking composition	Without 2D	With 2D Marking

(1) Lead color and surface finish change depending on lead finishing

(2) Package darkness changes depending on molding compound.

Pin1 identifier can change in terms of form and positioning.
Marking position and size could be different upon assembly site, without any loss of information.



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How can the change be seen?

Package top view Marking is:

	Existing Back-End Site	Added Back-End site
	Stats ChipPAC JSCC Jiangyin (China)	ST Muar (Malaysia)
LQFP 48		
PP code	GQ	99

PP code indicates assembly traceability plant code.

Please refer to product [DataSheet](#) or Technical Note **TN1433** for package marking details.



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How to order samples?

For all samples request linked to this PCN, please:

- place a **Non-standard** sample order (choose Sample Non Std Type from pull down menu)
- insert the PCN number "**PCN13956**" into the NPO Electronic Sheet/**Regional Sheet**
- request sample(s) through Notice tool, indicating a single Commercial Product for each request

Partial Ship: 01 Price Pol: 05 Status: 01 Canc:

%: 0 Sample Type: Sample Non Std Type

Closing Type: Sample Std Type
Sample Non Std Type
Sample Non Std w Spl Tests

Lab Sheet:

SO | NPO Sample

Header
SO Nr: 0018502433 Customer: 99770200 01 ST-TOKYO SO Type: 30 Sample Order Cost Center: JT3129 SAMPLES /SALES J
PO Nr: Carrier Code: 0001 Price Policy: 05 Currency: 02 U.S. DOLLAR Req Name:
Notes: Status: 01 All items pending,ni Issuing Date: 25-JUN-2018 Ord Val: 0.0000 Sample Req Date: 25-Jun-2018

Sch I Nr	PO I. Nr	Finished Good	Comm Qty	Open Qty	Plant Open Qty	Reqd Qty	Unit Price	RD	CD	EDD	St
1.1.10	000001	STM32F429NIH6	30	30	30	30	0.0000	25-Jun-18	01-Mar-59	01-Mar-59	01

Final Cust:
PO Item: 000001 Comm Prod: STM32F429NIH6 Qty: 30 RD: 25-Jun-18 Unit Price: 0.0000 Final Cust: 0000367006 SANSHIN/NPC

Cust Part Nr: Finished Good: Partial Ship: 01 Price Pol: 05 Status: 01 Canc:

Notes: TAM K Pieces: 0 Our Share: 0 Sample Type: Sample Non Std Type

Project Name: Closing Date: Closing Type:

Regional Sheet: **PCN 13956** Lab Sheet:



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MMS- MCD RER1514

Reliability Report

Qualification Type : ASSEMBLY LINE QUALIFICATION, NEW BILL OF MATERIALS

LQFP 7x7 48L - ST Muar Qualification

Extended listed products

(PCN9484)
(PCN13956)

Product / Process & Package Information	Die 410	Die 427	Die 765
Commercial Product:	STM32F103CBT6	STM32L152CCT6	STM8S207C8T6
Product Line:	STM32F die 410	STM32L die 427	STM8S die 765
Product Description:	Micro 32Bits		Micro 8Bits
Finish Good Code:	ES32F103CBT6\$J8	ES32L152CCT6\$B6	ES8S207C8T6\$9C
Mask Set Revision:	X410XXXX	X427XXXV	X765XXXV
Silicon Process Technology:	0.18 M8 EMBEDDED FLASH	8X - CMOSF9S	2V - CMOSF9
Wafer Fabrication Location:	TSMC Fab 3 Taiwan	ST Rousset 8 France	ST Rousset 8 France
Electrical Wafer Sort Test Plant Location:	ST MICROELECTRONICS Ang Mo Kio EWS SINGAPORE		ARDENTEC Hsinchu EWS Taiwan
Package:	LQFP 48 7x7x1.4		
Assembly Plant location:	ST Muar (Malaysia)		
Final Test plant location:	ST Muar (Malaysia)		

Approval List rev 1

Function	Location	Name	Date
Division Q&R Responsible	ST Rousset	Gisèle SEUBE	May31st, 2016
Division Quality Manager	ST Rousset	Pascal NARCHE	May31st, 2016

Approval List rev 2

Function	Location	Name	Date
Subgroup Quality Manager	ST Rousset	Pascal NARCHE	March 13 th , 2023

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1 RELIABILITY RESULTS OVERVIEW

1.1 Objectives

This report summarizes the reliability results for LQFP 48 7x7 package manufactured at ST Muar (Malaysia).

Test vehicles are described here below:

Product	Package
STM32F103CBT6	LQFP 48 7x7x1.4
STM32L152CCT6	LQFP 48 7x7x1.4
STM8S207C8T6	LQFP 48 7x7x1.4

1.2 Context

In order to increase assembly capacity, ST Microcontrollers Division has decided to add a High Density line in ST Muar (Malaysia) assembly site, for LQFP 48 7x7 products.

PCN9484 - Changes are described here below:

	Existing Bill Of Materials			Added Bill Of Materials
Assembly site	STATS ChipPAC Shanghai (China)	Amkor ATP (Philippines)	ST Muar (Malaysia)	ST Muar (Malaysia)
Wire	Gold 0.8mil	Gold 0.8mil	Gold 0.8mil	Silver 0.8mil
Leadframe	Copper Frame Spot Ag	Copper Frame Spot Ag	Pre Plated Frame	Pre Plated Frame
Leadfinishing (*1)	Pure Tin (e3)	Pure Tin (e3)	Rough Ni Pd AgAu (e4)	Rough Ni Pd AgAu (e4)
Resin	Sumitomo G700E	Sumitomo G631HQ	Sumitomo G700LS	Sumitomo G700LS
Glue	Ablestik 3230	Evertch AP4200	Hitachi EN4900	Hitachi EN4900

(*1) Lead color and surface finished change depending on leadfinishing

PCN13956 – Changes are described here below, for additional listed products (0.18µm TSMC) in PCN:

	Existing back-end site	Added back-end site
Assembly site	Stats ChipPAC JSCC Jiangyin (China)	ST Muar (Malaysia)
Wire	Gold 0.8mil	Silver 96.5% 0.8mil
Leadframe	Copper Frame Spot Ag	Pre Plated Frame
Leadfinishing (1)	Pure Tin (e3)	Rough Ni Pd AgAu (e4)
Resin (2)	Sumitomo G631SHQ	Sumitomo G700LS
Glue	Ablestik 3230	Hitachi EN4900
Marking composition	Without 2D	With 2D Marking

(1) Lead color and surface finish change depending on lead finishing

(2) Package darkness changes depending on molding compound

Changes are qualified using the standard STMicroelectronics Corporate Procedures for Quality and Reliability, in full compliancy with the JESD-47 international standard.

1.3 Conclusion

All reliability tests have been completed with positive results. Neither functional nor parametric rejects were detected at final electrical testing.

According to the positive reliability results, the qualification is granted for High Density assembly line in ST Muar (Malaysia) for CMOSF9S Rousset and CMOSF9 Rousset and TSMC0.18 (all diffusion plants TSMC are qualified by similarity with TSMC Fab3).

Refer to Section 3.0 for reliability test results.

2 RELIABILITY TEST VEHICLES Characteristics

2.1 Reliability Test vehicles description

Package line	Assembly Line	Package	Device (Partial RawLine Code)	Diffusion Process	Number of Lots
HD LQFP	LQFP7*7	48L	STM8S (5B*765)	F9GO1	1
			STM32F (5B*410)	TSMC 0.18µm	1
			STM32L (5B*427)	F9GO2S	1

2.2 Reliability Information

Lot ID	Lot 1	Lot 2	Lot 3
Die Name /cut:	410	427	765
Diffusion Lot Number:	93537129	VG536347	VG540309
Trace Code:	995510CH	995510CQ	995510CR
Assy lot number	995510CH01	995510CQ01	995510CR01
Raw Line Code Package:	J55B*410ESXX	U05B*427ESXV	J15B*765ESXV
Reliability Lab location :	ST Muar (Malaysia)		

2.3 Front-End information

Front-End	Lot 1 (410)	Lot 2 (427)	Lot 3 (765)
Wafer Diameter:	8 inches		
Wafer Thickness:	375 +/-25 μ m		
Die Size:	3.3908 X 3.328 mm	3.263 X 4.199 mm	3.010 X 2.458 mm
Scribe Line size x/y:	80 x 80 μ m		
Pad Die Size /Pad type:	59 x 123 μ m	53 x 108 μ m	65 x 108 μ m
Metal Layers Number /Materials /Thickness:	Metal 1 Tin/AlCu/Tin 0.450 μ m Metal 2 Tin/AlCu/Tin 0.450 μ m Metal 3 Tin/AlCu/Tin 0.450 μ m Metal 4 Tin/AlCu/Tin 0.450 μ m Metal 5 Tin/AlCu/Tin 0.875 μ m	Metal 1 TaN/Ta/Cu 0.280 μ m Metal 2 Ti/AlCu/TxTN 0.310 μ m Metal 3 Ti/AlCu/TxTN 0.310 μ m Metal 4 Ti/AlCu/TxTN 0.310 μ m Metal 5 Ti/AlCu/TxTN 1.200 μ m	Metal 1 TaN/Ta/Cu 0.280 μ m Metal 2 TaN/Ta/Cu 0.350 μ m Metal 3 TaN/Ta/Cu 0.350 μ m Metal 4 Ti/AlCu/TxTN 0.900 μ m
Passivation Layers Thickness:	HDPox 10kA+SRO 1.5kA+PESIN 6kA	USG + NitUV (HFP USG+UV Nitride)	
Back Metal Finishing	RAW SILICON - BACK GRINDING		

2.4 Back-End information

Back-End	Lot 1 (410)	Lot 2 (427)	Lot 3 (765)
Assembly Plant Location/ Address:	ST MICROELECTRONICS TANJONG AGAS IND ESTATE PO BOX 28 84007 MUAR / JOHOR MALAYSIA		
Die Thickness after Back grinding:	NA	NA	NA
Die sawing method:	Step cut		
Die attach material:	Glue		
Type:	EN4900		
Supplier:	ST16		
Lead frame material:	Copper LF-HD LQFP 48L 7x7		Copper LF-HD LQFP 48L 7x7
L/F Finishing Type:	Rough μ PPF (e4) Ni Pd AuAg		Rough μ PPF (e4) Ni Pd AuAg
Die paddle size:	5 x 5		3.6 x 3.6
Supplier:	HDS		HDS
Wire bonding:	AG 96,5% WIRE		
Type	0.8MIL		
/Diameter:	MKE		
Supplier:			
Pitch:	80 μ m	70 μ m	80,36 μ m
POA:	0110596		
Molding Compound Supplier:	EME-G700LS SUMITOMO		
Package Moisture Sensitivity Level (JEDEC J-STD020D):	2		

3 RELIABILITY RESULTS SUMMARY

3.1 Die oriented test

Die Related Tests						Results LQFP 7x7		
Description	Test/Method	Conditions	Sample Size	Criteria	Readout / Duration	410	427	765
<i>Electrostatic discharge – Charge Device Model</i>								
ESD CDM	ANSI/ESD STM5.3.1	500V 1KV	3 units	500V for dice 410/427 1KV for 765	NA	0/3	0/3	0/3

3.2 Package Oriented Test

Package Related Tests						Results LQFP 7x7		
Description	Test/Method	Conditions	Sample Size	Criteria	Readout / Duration	410	427	765
<i>Preconditioning: moisture sensitivity level 1</i>								
PC	J-STD-020 JESD22-A113	MSL1 For MSL2 Qual	308 units	Electrical test: A0/R1 (Accepted 0 reject/ Rejected 1 reject)	NA	0/308		
<i>High Temperature Storage Life</i>								
HTSL	JESD 22-A103	150°C	77 units	Elect test A0/R1	1000h	0/77	0/77	0/77
<i>Thermal Cycling after Preconditioning</i>								
TC	JESD 22-A104	-65c/+150°c	77 units	Elect test A0/R1	100cy	0/77	0/77	0/77
					500cy	0/77	0/77	0/77
					1000cy	0/77	0/77	0/77
<i>Wire Bond Shear after Thermal Cycling</i>								
Wire Bond Shear	AEC Q100-001	Min bond shear 15g after TC	30 x 3	A0/R1	After TC 500cy TC 1000cy	0/30	0/30	0/30
<i>Wire Bond Pull after Thermal Cycling</i>								
Wire Bond Pull	Mil Std 883 Method 2011	Minimum pull strength after TC=3 grams after TC	30 x 3	A0/R1	After TC 500cy TC 1000cy	0/30	0/30	0/30

<i>Autoclave after Preconditioning</i>									
AC	JESD 22A102	121°C ,100% 2Atm RH	77 units	Elect test A0/R1	96h	0/77	0/77	0/77	
<i>Temperature Humidity Bias after Preconditioning</i>									
THB	JESD 22A110	85°C/85%RH Bias	77 units	Elect test A0/R1	1000h	0/77	0/77	0/77	
<i>Construction Analysis</i>									
CA	Construction Analysis including : -Wire bond shear -Wire bond pull -Solderability -Physical Dimension	JESD 22B102 JESDB100/B108	50		No major concern	No major concern			

4 APPLICABLE AND REFERENCE DOCUMENTS

ADCS/DMS 0061692 :	Reliability Tests And Criteria For Qualifications
SOP 2.6.2:	Process qualification and transfer management
SOP 2.6.7:	Product Maturity Level
SOP 2.6.9:	Package and process maturity management in Back End
SOP 2.6.11:	Program management from product qualification
SOP 2.6.19:	Process maturity level
ANSI-ESD STM5.3.1:	Electrostatic discharge (ESD) sensitivity testing charge device model (CDM)
JESD 22-A103	High Temperature Storage Life
J-STD-020D:	Moisture/reflow sensitivity classification for non-hermetic solid state surface mount devices
JESD22-A113:	Preconditioning of non-hermetic surface mount devices prior to reliability testing
JESD22-A102:	Autoclave test (pressure pot)
JESD22-A104:	Temperature cycling
JESD22-A110:	Temperature Humidity Bake
JESD 22B102:	Solderability test
JESD22B100/B108:	Physical dimension

5 GLOSSARY AND TESTS DESCRIPTION

PC	Preconditioning (solder simulation)
THB	Temperature Humidity Bias
TC	Temperature cycling
AC	Autoclave test (pressure pot)
HTSL	High temperature storage life
ADCS/DMS	ST Advanced Documentation Controlled system/ Documentation Management system
ESD CDM	Electrostatic discharge (charge device model)
CA	Construction Analysis

6 REVISION HISTORY

Version	Date	Author	Comment
1.0	May 31st, 2016	Olivier GIRAUD	Initial release for qualification
2.0	March 13th, 2023	Berengere ROUTIER-SCAPPUCCI	Added new PCN13956 for additional products

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